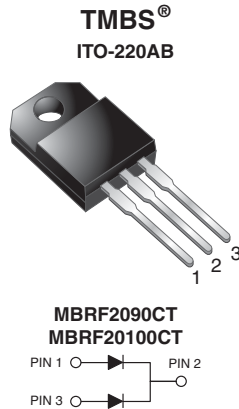


## Dual High-Voltage Trench MOS Barrier Schottky Rectifier



### FEATURES

- Trench MOS Schottky technology
- Low power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

### MECHANICAL DATA

**Case:** ITO-220AB

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 10 A
$V_{RRM}$	90 V, 100 V
$I_{FSM}$	150 A
$V_F$ at $I_F = 10$ A	0.65 V
$T_J$ max.	150 °C
Package	ITO-220AB
Diode variation	Dual common cathode

MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)				
PARAMETER	SYMBOL	MBRF2090CT	MBRF20100CT	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	90	100	V
Working peak reverse voltage	$V_{RWM}$	90	100	V
Maximum DC blocking voltage	$V_{DC}$	90	100	V
Maximum average forward rectified current at $T_C = 133$ °C	$I_{F(AV)}$	total device		A
		per diode		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	150		A
Voltage rating of change (rated $V_F$ )	dV/dt	10 000		V/μs
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +150		°C
Isolation voltage from terminal to heatsink t = 1 min	$V_{AC}$	1500		V



<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage per diode	$I_F = 10\text{ A}$	$T_C = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.80	V
		$T_C = 125\text{ }^\circ\text{C}$		0.65	
	$I_F = 20\text{ A}$			0.75	
Maximum reverse current per diode at working peak reverse voltage			$I_R^{(2)}$	100	$\mu\text{A}$
				6.0	mA

**Notes**

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width  $\leq 40\text{ ms}$

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	MBRF	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	3.5	$^\circ\text{C/W}$

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	MBRF20100CT-M3/4W	1.75	4W	50/tube	Tube

**RATINGS AND CHARACTERISTICS CURVES** ( $T_C = 25\text{ }^\circ\text{C}$  unless otherwise noted)

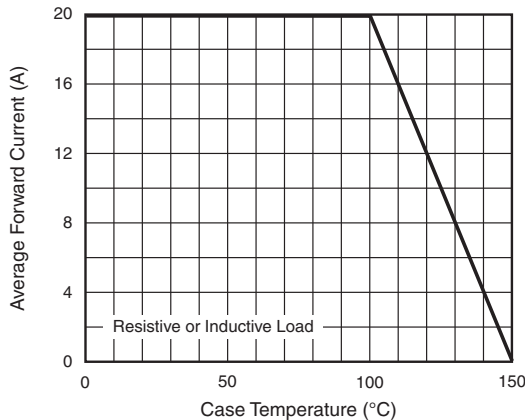


Fig. 1 - Forward Current Derating Curve

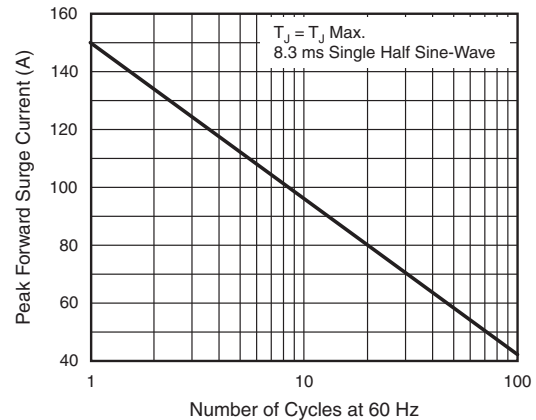


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

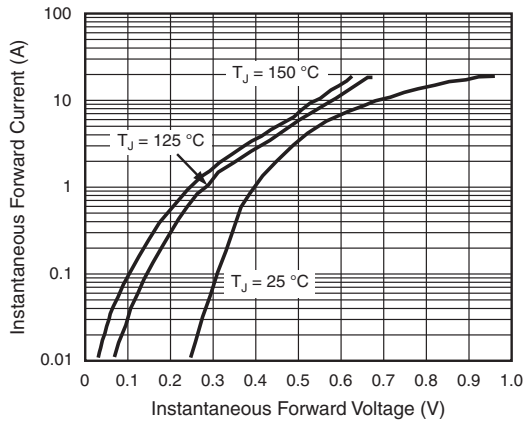


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

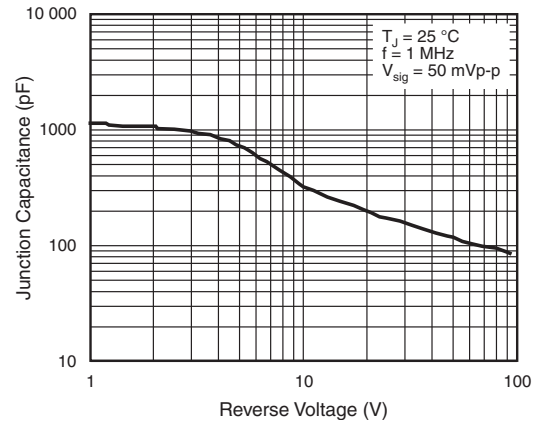


Fig. 5 - Typical Junction Capacitance Per Diode

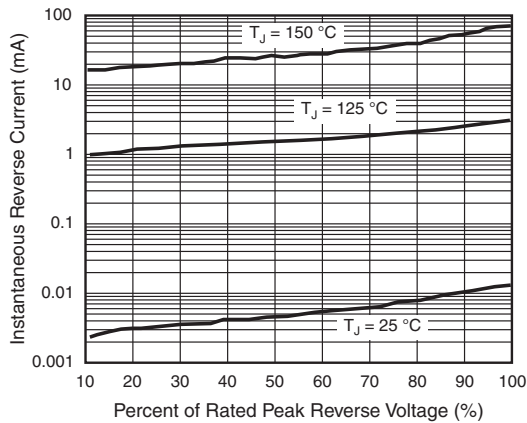


Fig. 4 - Typical Reverse Characteristics Per Diode

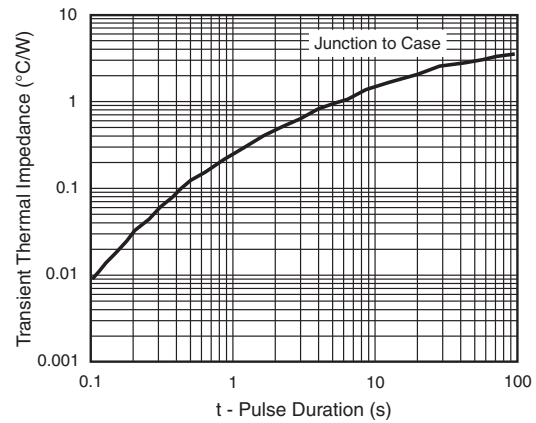
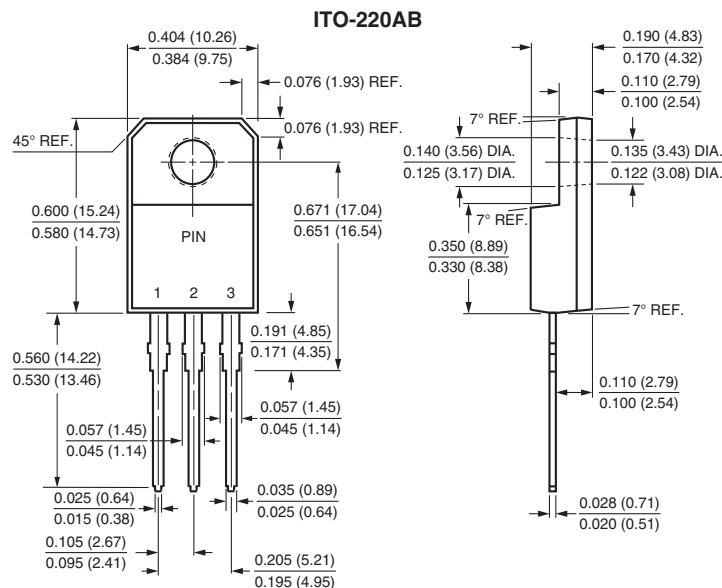


Fig. 6 - Typical Transient Thermal Impedance Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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